



#### **1A STEP-DOWN DC-DC CONVERTER**

#### **Description**

The PAM2305D is a step-down current-mode, DC-DC converter. At heavy load, the constant frequency PWM control per forms excellent stability and transient response. To ensure the longest battery life in portable applications, the PAM2305D provides a power-saving Pulse-Skipping Modulation (PSM) mode to reduce quiescent current under light load operation to save power.

The PAM2305D supports a range of input voltages from 2.5V to 5.5V, allowing the use of a single Li+/Li-polymer cell, multiple Alkaline/NiMH cell, USB, and other standard power sources. The output voltage is adjustable from 0.6V to the input voltage. All versions employ internal power switch and synchronous rectifier to minimize external part count and realize high efficiency. During shutdown, the input is disconnected from the output and the shutdown current is less than 0.1 $\mu$ A. Other key features include under-voltage lockout to prevent deep battery discharge.

The PAM2305D is available in TSOT25, DFN2x2-6 Pin and QFN3x3-16 Pin packages.

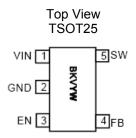
#### **Features**

- Efficiency up to 96%
- Only 40μA (typ) Quiescent Current
- Output Current: Up to 1A
- Internal Synchronous Rectifier
- 1.5MHz Switching Frequency
- Soft Start
- Under-Voltage Lockout
- Short Circuit Protection
- Thermal Shutdown
- 5-pin Small TSOT25, DFN2x2-6 Pin and QFN3x3-16 Pin Packages
- Pb-Free Packages

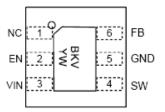
### **Applications**

- Cellular Phone
- Portable Electronics
- Wireless Devices
- Cordless Phone
- Computer Peripherals
- Battery Powered Widgets
- Electronic Scales
- Digital Frame

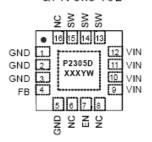
### Pin Assignments



Top View DFN 2x2 6L

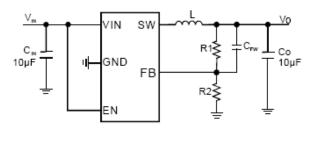


Top View QFN 3x3 16L





# **Typical Applications Circuit**

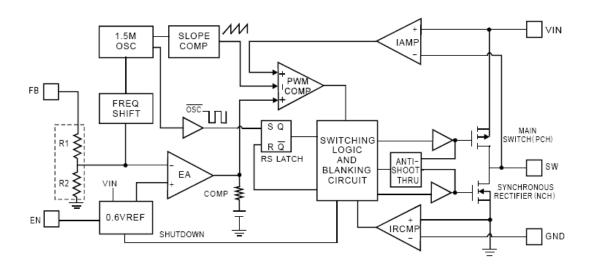


$$V_O = 0.6 \times \left(1 + \frac{R1}{R2}\right)$$

### **Pin Descriptions**

Pin	Package Name			Function	
Name	TSOT25	DFN2x2-6L	QFN3x3-16L	FullClion	
VIN	1	3	9, 10, 11, 12	Chip main power supply pin.	
GND	2	5	1, 2, 3, 5	Ground.	
EN	3	2	7	Enable Control Input. Force this pin voltage above 1.5V, enables the chip, and below 0.3V shuts down the device.	
FB	4	6	4	Feedback voltage to internal error amplifier, the threshold voltage is 0.6V.	
SW	5	4	13, 14, 15	The drains of the internal main and synchronous power MOSFET.	
NC		1	6, 8, 16	No connection.	

### **Functional Block Diagram**







# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods may affect device reliability. All voltages are with respect to ground.

Parameter	Rating	Unit
Input Voltage	-0.3 to +6.0	V
EN, FB Pin Voltage	-0.3 to V <sub>IN</sub>	V
SW Pin Voltage	-0.3 to (V <sub>IN</sub> +0.3)	V
Junction Temperature	150	°C
Storage Temperature Range	-65 to +150	°C
Soldering Temperature	300, 5sec	°C

# Recommended Operating Conditions (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter	Rating	Unit
Supply Voltage	2.5 to 5.5	V
Operation Temperature Range	-40 to +85	°C
Junction Temperature Range	-40 to +125	

### **Thermal Information**

Parameter	Package	Symbol	Max	Unit
	TSOT25 (Note 1)		130	
Thermal Resistance (Junction to Case)	DFN2x2-6	$\theta_{JC}$	25	
	QFN3x3-16		14	°C/W
	TSOT25		250	C/VV
Thermal Resistance (Junction to Ambient)	DFN2x2-6	$\theta_{JA}$	68	
	QFN3x3-16		35	
	TSOT25		400	mW
Internal Power Dissipation	DFN2x2-6	$P_{D}$	980	
	QFN3x3-16		1470	

Note:

<sup>1.</sup> The maximun output current for TSOT25 package is limited by internal power dissipation capacity as described in Application Information here inafter





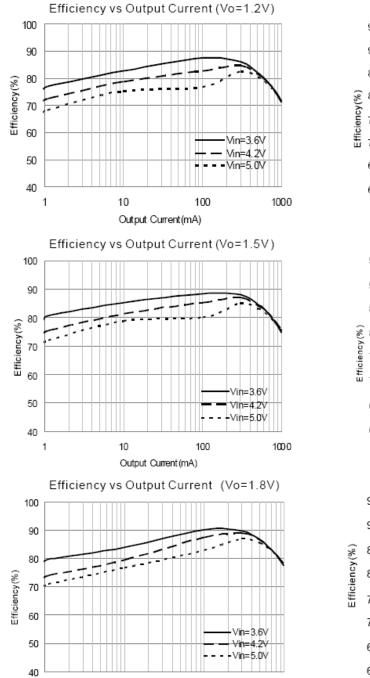
# $\hline \textbf{Electrical Characteristics} \ (@T_A = +25^{\circ}C, \ V_{IN} = 3.6V, \ V_O = 1.8V, \ C_{IN} = 10 \mu F, \ C_{OUT} = 10 \mu F, \ L = 4.7 \mu H, \ unless \ otherwise \ specified.)$

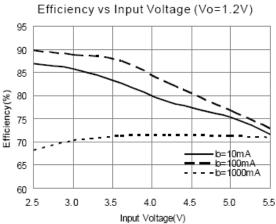
Parameter	Symbol	Test Conditions		Min	Тур	Max	Units
Input Voltage Range	V <sub>IN</sub>			2.5		5.5	V
Regulated Feedback Voltage	V <sub>FB</sub>	Io = 100mA		0.588	0.6	0.612	V
Reference Voltage Line Regulation	$\Delta V_{FB}$				0.3		%/V
Regulated Output Voltage Accuracy	Vo	I <sub>O</sub> = 100mA		-3		+3	%
Peak Inductor Current	I <sub>PK</sub>	V <sub>IN</sub> = 3V,V <sub>FB</sub> = 0.5V	or V <sub>O</sub> = 90%		1.5		Α
Output Voltage Line Regulation	LNR	$V_{IN} = 2.5V \text{ to } 5V, I_{O}$	= 10mA		0.2	0.5	%/V
Output Voltage Load Regulation	LDR	I <sub>O</sub> = 1mA to 800mA			1.5		%
Quiescent Current	IQ	No load			40	70	μA
Shutdown Current	I <sub>SD</sub>	V <sub>EN</sub> = 0V			0.1	1	μA
One: Heten Francisco		V <sub>O</sub> = 100%		1.2	1.5	1.8	MHz
Oscillator Frequency	fosc	V <sub>FB</sub> = 0V or V <sub>O</sub> = 0V			500		kHz
Drain-Source On-State Resistance	Б	I <sub>DS</sub> = 100mA	P MOSFET		0.3	0.45	Ω
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>		N MOSFET		0.35	0.5	Ω
SW Leakage Current	I <sub>LSW</sub>				±0.01	1	μA
EN Threshold High	V <sub>EH</sub>			1.5			V
EN Threshold Low	V <sub>EL</sub>					0.3	V
EN Leakage Current	I <sub>EN</sub>				±0.01		μA
Over Temperature Protection	OTP				150		°C
OTP Hysteresis	OTH				30		°C

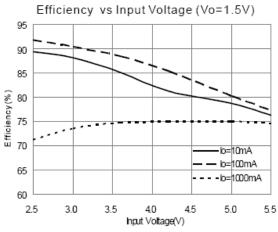


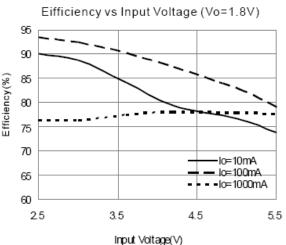


### Typical Performance Characteristics ( $@T_A = +25^{\circ}C$ , $C_{IN} = 10\mu F$ , $C_O = 10\mu F$ , $L = 4.7\mu H$ , unless otherwise specified.)









1

10

1000

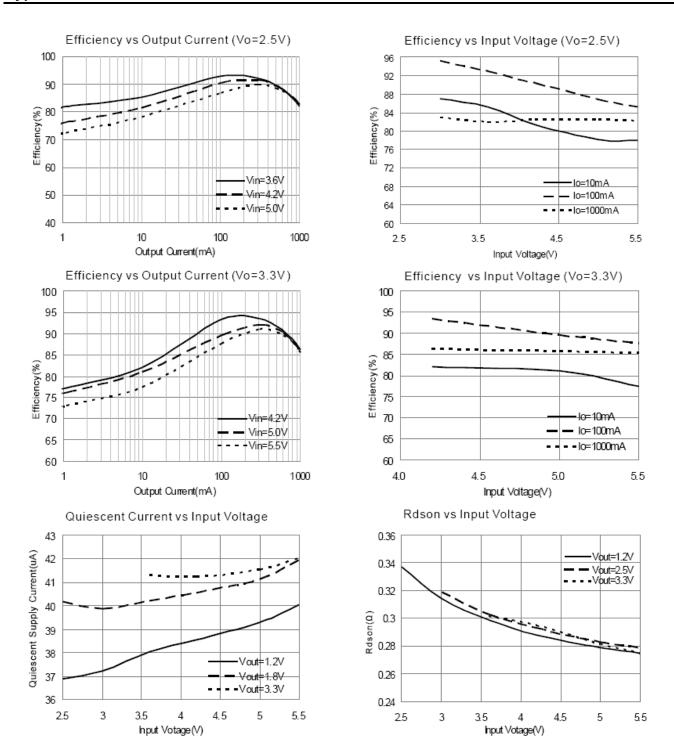
100

Output Current(mA)



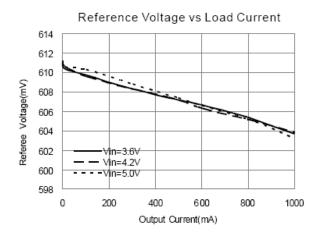


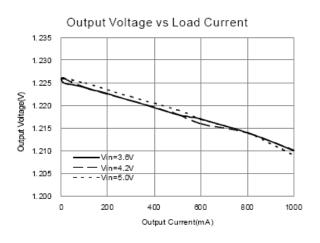
## Typical Performance Characteristics (cont.) (@T<sub>A</sub> = +25°C, C<sub>IN</sub> = 10μF, C<sub>O</sub> = 10μF, L = 4.7μH, unless otherwise specified.)

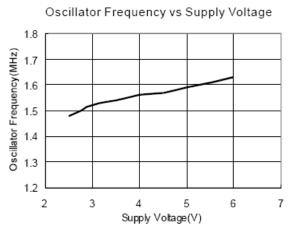


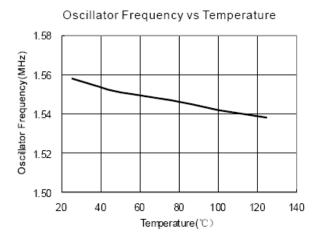


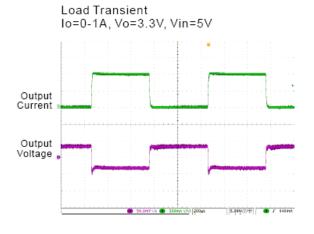
# $\textbf{Typical Performance Characteristics} \ (cont.) \ (@T_A = +25^{\circ}C, \ C_{IN} = 10 \mu F, \ C_O = 10 \mu F, \ L = 4.7 \mu H, \ unless \ otherwise \ specified.)$

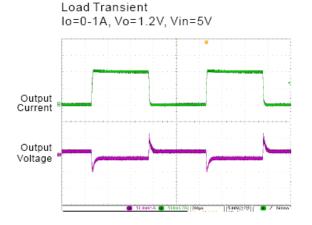














### **Application Information**

The basic PAM2305D application circuit is shown in Page 2. External component selection is determined by the load requirement, selecting L first and then  $C_{IN}$  and  $C_{OUT}$ .

#### **Inductor Selection**

For most applications, the value of the inductor will fall in the range of  $1\mu$ H to  $4.7\mu$ H. Its value is chosen based on the desired ripple current. Large value inductors lower ripple current and small value inductors result in higher ripple currents. Higher  $V_{IN}$  or  $V_{OUT}$  also increases the ripple current as shown in Equation 1. A reasonable starting point for setting ripple current is  $\Delta I_L = 400$ mA (40% of 1A).

$$\Delta I_{L} = \frac{1}{(f)(L)} V_{OUT} \left( 1 - \frac{V_{OUT}}{V_{IN}} \right)$$
 Equation (1)

The DC current rating of the inductor should be at least equal to the maximum load current plus half the ripple current to prevent core saturation. Thus, a 1.4A rated inductor should be enough for most applications (1A + 400mA). For better efficiency, choose a low DC-resistance inductor.

Vo	1.2V	1.5V	1.8V	2.5V	3.3V
L	2.2µH	2.2µH	2.2µH	4.7µH	4.7µH

#### CIN and COUT Selection

In continuous mode, the source current of the top MOSFET is a square wave of duty cycle V<sub>OUT</sub>/V<sub>IN</sub>. To prevent large voltage transients, a low ESR input capacitor sized for the maximum RMS current must be used. The maximum RMS capacitor current is given by:

$$C_{IN} required |_{RMS} \cong |_{OMAX} \frac{\left[V_{OUT} \left(V_{IN} - V_{OUT}\right)\right]^{1/2}}{V_{IN}}$$

This formula has a maximum at  $V_{IN} = 2V_{OUT}$ , where  $I_{RMS} = I_{OUT}/2$ . This simple worst-case condition is commonly used for design because even significant deviations do not offer much relief. Note that the capacitor manufacturer's ripple current ratings are often based on 2000 hours of life. This makes it advisable to further derate the capacitor, or choose a capacitor rated at a higher temperature than required. Consult the manufacturer if there is any question.

The selection of C<sub>OUT</sub> is driven by the required effective series resistance (ESR).

Typically, once the ESR requirement for  $C_{OUT}$  has been met, the RMS current rating generally far exceeds the  $I_{RIPPLE}$  (P-P) requirement. The output ripple  $\Delta V_{OUT}$  is determined by:

$$\Delta V_{OUT} \cong \Delta i_L \left( ESR + \frac{1}{8f C_{OUT}} \right)$$

Where f = operating frequency,  $C_{OUT}$  = output capacitance and  $\Delta I_L$  = ripple current in the inductor. For a fixed output voltage, the output ripple is highest at maximum input voltage since  $\Delta I_L$  increases with input voltage.

#### **Using Ceramic Input and Output Capacitors**

Higher values, lower cost ceramic capacitors are now becoming available in smaller case sizes. Their high ripple current, high voltage rating and low ESR make them ideal for switching regulator applications. Using ceramic capacitors can achieve very low output ripple and small circuit size.

When choosing the input and output ceramic capacitors, choose the X5R or X7R dielectric formulations. These dielectrics have the best temperature and voltage characteristics of all the ceramics for a given value and size.

#### **Thermal Consideration**

Thermal protection limits power dissipation in the PAM2305D. When the junction temperature exceeds 150°C, the OTP (Over Temperature Protection) starts the thermal shutdown and turns the pass transistor off. The pass transistor resumes operation after the junction temperature drops below +120°C.

For continuous operation, the junction temperature should be maintained below +125°C.

The power dissipation is defined as:

$$P_{D} = I_{O}^{2} \frac{V_{O} R_{DS(ON)H} + (V_{IN} - V_{O}) R_{DS(ON)L}}{V_{IN}} + (t_{SW} F_{S} I_{O} + I_{Q}) V_{IN}$$

 $I_Q$  is the step-down converter quiescent current. The term tsw is used to estimate the full load step-down converter switching losses.



### **Application Information (cont.)**

For the condition where the step-down converter is in dropout at 100% duty cycle, the total device dissipation reduces to:

$$P_D = I_O^2 R_{DS(ON)H} + I_O V_{IN}$$

Since R<sub>DS(ON)</sub>, quiescent current, and switching losses all vary with input voltage, the total losses should be investigated over the complete input voltage range. The maximum power dissipation depends on the thermal resistance of IC package, PCB layout, the rate of surrounding airflow and temperature difference between junction and ambient. The maximum power dissipation can be calculated by the following formula:

$$P_D = \frac{T_{J(MAX)} - T_A}{\theta_{JA}}$$

Where  $T_{J(MAX)}$  is the maximum allowable junction temperature +125°C.  $T_A$  is the ambient temperature and  $\theta_{JA}$  is the thermal resistance from the junction to the ambient. Based on the standard JEDEC for a two layers thermal test board, the thermal resistance  $\theta_{JA}$  of TSOT25 package is 250°C/W, DFN2X2 102°C/W and QFN3X3 68°C/W, respectively. The maximum power dissipation at  $T_A$  = +25°C can be calculated by following formula:

SOT-25 package:

$$P = (125^{\circ}C - 25^{\circ}C)/250^{\circ}C/W = 0.4W$$

DFN2\*2 package:

$$P = (125^{\circ}C - 25^{\circ}C)/102^{\circ}C/W = 0.984W$$

QFN3\*3 package:

$$P = (125^{\circ}C - 25^{\circ}C)/68^{\circ}C/W = 1.47W$$

#### **Setting the Output Voltage**

The internal reference is 0.6V (Typical). The output voltage is calculated as below:

$$V_O = 0.6 \times \left(1 + \frac{R1}{R2}\right)$$

The output voltage is given by Table 1.

Table 1:Resistor selection for output voltage setting.

Vo	R1	R2
1.2V	100k	100k
1.5V	150k	100k
1.8V	200k	100k
2.5V	380k	120k
3.3V	540k	120k

#### 100% Duty Cycle Operation

As the input voltage approaches the output voltage, the converter turns the P-Channel transistor continuously on. In this mode the output voltage is equal to the input voltage minus the voltage drop across the P-Channel transistor:

$$V_{OUT} = V_{IN} - I_{LOAD} (R_{DS(ON)} + R_L)$$

where  $R_{DS(ON)}$  = P-Channel switch ON resistance,  $I_{LOAD}$  = Output current,  $R_L$  = Inductor DC resistance.

#### **UVLO and Soft-Start**

The reference and the circuit remain reset until the V<sub>IN</sub> crosses its UVLO threshold.

The PAM2305D has an internal soft-start circuit that limits the in-rush current during start-up. This prevents possible voltage drops of the input voltage and eliminates the output voltage overshoot. The soft-start acts as a digital circuit to increase the switch current in several steps to the P-Channel current limit (1500mA).

#### **Short Circuit Protection**

The switch peak current is limited cycle-by-cycle to a typical value of 1500mA. In the event of an output voltage short circuit, the device operates with a frequency of 400kHz and minimum duty cycle, therefore the average input current is typically 200mA.





### **Application Information (cont.)**

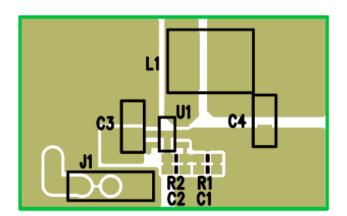
#### **Thermal Shutdown**

When the die temperature exceeds +150°C, a reset occurs and the reset remains until the temperature decrease to +120°C, at which time the circuit can be restarted.

#### **PCB Layout Check List**

When laying out the printed circuit board, the following checklist should be used to ensure proper operation of the PAM2305D. These items are also illustrated graphically in Figure 1. Check the following in your layout:

- 1. The power traces, consisting of the GND trace, the SW trace and the V<sub>IN</sub> trace should be kept short, direct and wide.
- 2. Does the  $V_{FB}$  pin connect directly to the feedback resistors? The resistive divider R1/R2 must be connected between the (+) plate of  $C_{OUT}$  and ground.
- 3. Does the (+) plate of  $C_{IN}$  connect to  $V_{IN}$  as closely as possible? This capacitor provides the AC current to the internal power MOSFETs.
- 4. Keep the switching node, SW, away from the sensitive V<sub>FB</sub> node.
- 5. Keep the (-) plates of C<sub>IN</sub> and C<sub>OUT</sub> as close as possible.



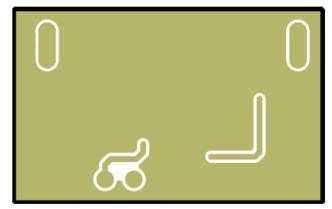
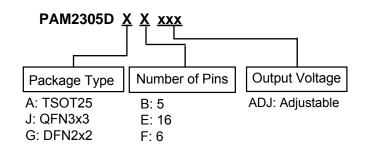


Figure 1. PAM2305D Suggested Layout

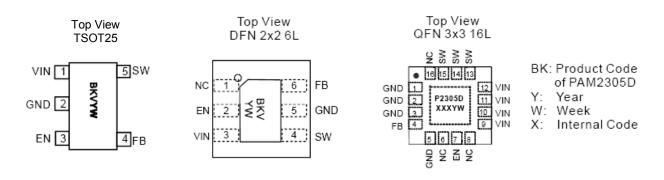


### **Ordering Information**



Part Number	Output Voltage	Part Marking	Package Type	Standard Package
PAM2305DABADJ	ADJ	BKAYW	TSOT25	3000 Units/Tape&Reel
PAM2305DJEADJ	ADJ	P2305D	QFN3x3	3000 Units/Tape&Reel
PAM2305DGFADJ	ADJ	BKAYW	DFN2x2-6	3000 Units/Tape&Reel

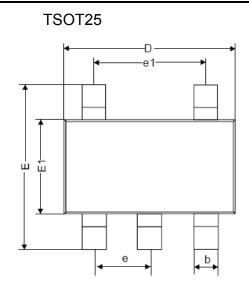
### **Marking Information**

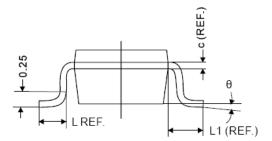


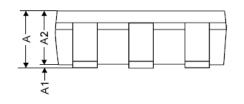




# Package Outline Dimensions (All dimensions in mm.)







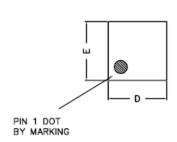
פרר	Millimeter		
REF.	Min	Max	
Α	1.10 N	ΛΑΧ	
A1	0	0.10	
A2	0.70	1	
O	0.12 F	REF.	
О	2.70	3.10	
Е	2.60	3.00	
E1	1.40	1.80	
L	0.45 REF.		
L1	0.60 REF.		
θ	0°	10°	
р	0.30	0.50	
е	0.95 REF.		
e1	1.90 REF.		



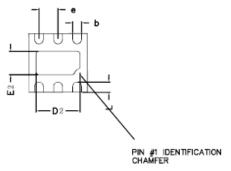


### Package Outline Dimensions (cont.) (All dimensions in mm.)

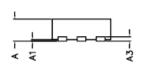
### DFN 2x2



TOP VIEW



BOTTOM VIEW



SIDE VIEW

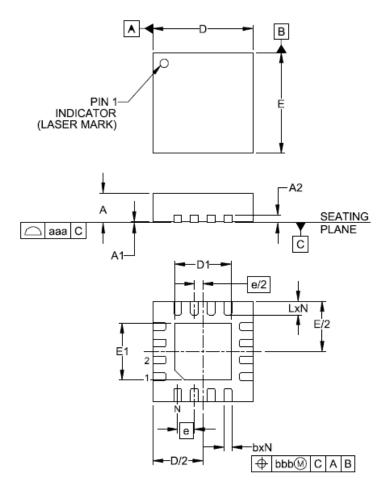
COMMON DIMENSIONS(MM)							
PKG.	W:	VERY VERY	ΓΗΙΝ				
REF.	MIN.	NOM.	MAX				
Α	0.70	0.75	0.80				
A1	0.00	_	0.05				
А3		0.2 REF.					
D	1.95	2.00	2.05				
E	1.95	2.00	2.05				
Ь	0.25	0.30	0.35				
L	0.25	0.35	0.45				
D2	1.35	1.50	1.60				
E2	0.65	0.80	0.90				
е	0.65 BSC						





### Package Outline Dimensions (cont.) (All dimensions in mm.)

### 3x3 mm QFN 16



DIMENSIONS (Millieters)						
	MIN	TYP	MAX			
Α	0.70	0.75	0.80			
A1	0.00	0.02	0.05			
A2		0.20				
b	0.18	0.25	0.30			
D	2.90	3.00	3.10			
D1	1.55	1.70	1.80			
Ε	2.90	3.00	3.10			
E1	1.55	1.70	1.80			
е		0.50BSC	;			
L	0.30	0.40	0.50			
N	16					
aaa	0.08					
bbb	0.10					
	•					

Notes:

- Controlling dimensions are in millimeters (angles in degress).
  Coplanarity applies to the exposed pad as well as the terminals.
  DAP is 1.90 x 1.90mm.





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